

# isc N-Channel Mosfet Transistor

# **STFW69N65M5**

#### • FEATURES

- Drain Current ID= 58A@ TC=25  $^{\circ}\mathrm{C}$
- · Drain Source Voltage-
  - : V<sub>DSS</sub>= 650V(Min)
- · Fast Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### APPLICATIONS

Switching applications

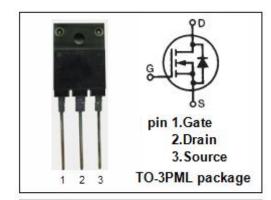


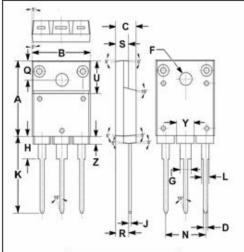
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	650	V
V <sub>GS</sub>	Gate-Source Voltage	±25	V
I <sub>D</sub>	Drain Current-continuous@ T <sub>C</sub> =25°C	58	Α
I <sub>DM</sub>	Pulse Drain Current	232	Α
P <sub>tot</sub>	Total Dissipation@T <sub>C</sub> =25℃	79	W
Tj	Max. Operating Junction Temperature	150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature Range	-55~150	$^{\circ}$

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	1.58	°C/W





	mm		
DIM	MIN	MAX	
Α	19.90	20.10	
В	15.75	16.10	
C	5.50	5.70	
D	0.90	1.10	
F	3.30	3.50	
G	2.90	3.20	
Н	5.90	6.10	
J	0.595	0.70	
K	21.10	22.50	
L	1.90	2.25	
N	10.80	11.00	
0	4.90	5.10	
Ŗ	3.75	3.95	
S	3.20	3.60	
U	9.90	10.10	
Y	4.20	4.90	
Z	1.90	2.10	



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#### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 1mA	650			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =250μA	3		5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 29A			45	mΩ
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±25V;V <sub>DS</sub> = 0			±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = Max rating			1	- μΑ
		V <sub>DS</sub> = Max rating; T <sub>C</sub> =125℃			100	
V <sub>SD</sub>	Diode Forward On-Voltage	I <sub>S</sub> = 58A ;V <sub>GS</sub> = 0			1.5	V

#### **NOTICE:**

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